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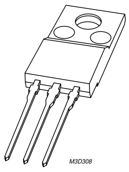


BUT12AX

Silicon diffused power transistor

Rev. 01 — 16 June 2004 **Product data**

1. Product profile

1.1 Description

High voltage, high speed, NPN power transistor in a plastic package.

1.2 Features

- Isolated package
- Fast switching.

1.3 Applications

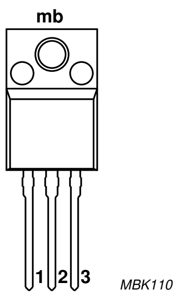
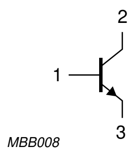
- Inverters
- Motor control systems
- Switching regulators
- DC-to-DC converters.

1.4 Quick reference data

- $V_{CESM} \leq 1000$ V
- $P_{tot} \leq 23$ W
- $I_C \leq 8$ A
- $t_f \leq 0.8$ µs.

2. Pinning information

Table 1: Pinning - SOT186A (TO-220F), simplified outline and symbol

Pin	Description	Simplified outline	Symbol
1	base (b)	 SOT186A (TO-220F)	
2	collector (c)		
3	emitter (e)		
mb	mounting base; isolated		

3. Ordering information

Table 2: Ordering information

Type number	Package		
	Name	Description	Version
BUT12AX	TO-220F	Plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3 leads.	SOT186A

4. Limiting values

Table 3: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CESM}	peak collector-emitter voltage	V_{BE} = 0 V		-	1000	V
V_{CEO}	collector-emitter voltage	base open circuit		-	450	V
I_C	collector current	Figure 2 and 3		-	8	A
I_{Csat}	collector saturation current			-	5	A
I_{CM}	peak collector current	Figure 3		-	20	A
I_B	base current (DC)			-	4	A
I_{BM}	peak base current			-	6	A
P_{tot}	total power dissipation	T_h = 25 °C; Figure 1	[1]	-	23	W
T_{stg}	storage temperature			–65	+150	°C
T_j	junction temperature			-	+150	°C

[1] Mounted without heatsink compound.

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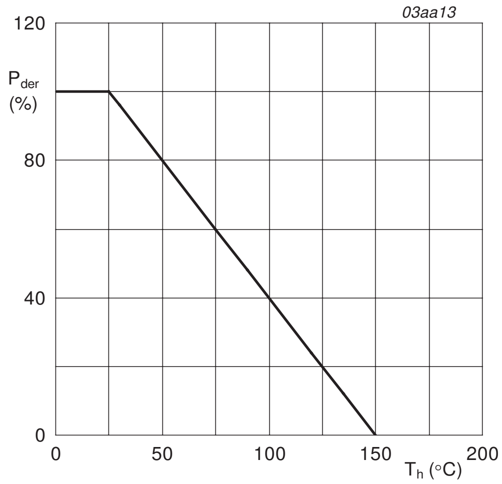
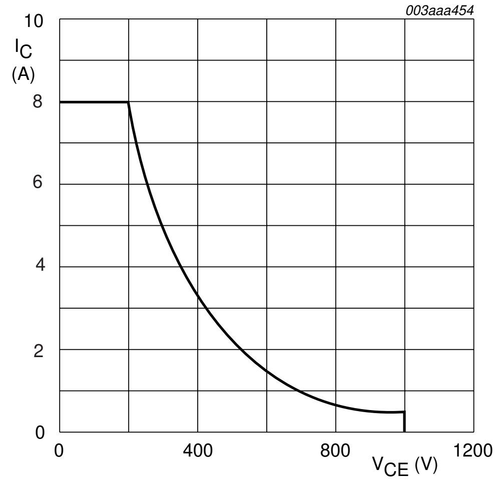


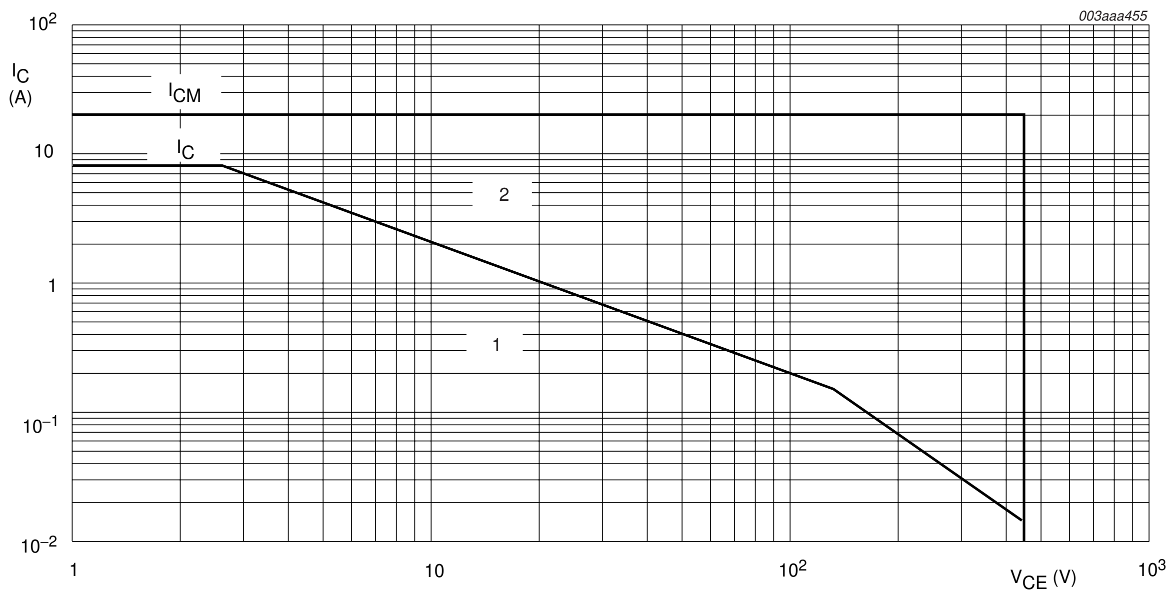
$$P_{der} = \frac{P_{tot}}{P_{tot(25°C)}} \times 100\%$$

Fig 1. Normalized total power dissipation as a function of heatsink temperature.



V_{BE} = −1 V to −5 V; T_h = 100 °C.

Fig 2. Reverse bias safe operating area; continuous collector current as a function of collector-emitter voltage.



T_h = 25 °C

1 - Region of permissible DC operation.

2 - Permissible extension for repetitive operation.

Fig 3. Forward bias safe operating area; continuous and peak collector currents as a function of collector-emitter voltage.

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5. Thermal characteristics

Table 4: Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-h)}$	thermal resistance from junction to heatsink	Mounted without heatsink compound	[1]	-	-	5.5	K/W
		Mounted with heatsink compound	[1]	-	-	3.9	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient			-	55	-	K/W

[1] External heatsink connected to mounting base.

6. Characteristics

Table 5: Characteristics

T_j = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
V_{CEOsus}	collector-emitter sustaining voltage	I_C = 100 mA; I_{Boff} = 0 A; L = 25 mH; Figure 9 and 10		400	-	-	V
V_{CEsat}	collector-emitter saturation voltage	I_C = 5 A; I_B = 1 A; Figure 5		-	-	1.5	V
V_{BEsat}	base-emitter saturation voltage	I_C = 5 A; I_B = 1 A; Figure 4		-	-	1.5	V
I_{CES}	collector-emitter cut-off current	V_{CE} = V_{CESM}; V_{BE} = 0 V					
		T_j = 25 °C	[1]	-	-	1	mA
		T_j = 125 °C	[1]	-	-	3	mA
h_{FE}	DC current gain	V_{CE} = 5 V; Figure 8					
		I_C = 10 mA		10	18	35	
		I_C = 1 A		10	20	35	
Dynamic characteristics							
t_{on}	turn-on time	I_{Con} = 5 A; I_{Bon} = I_{Boff} = 1 A; resistive load; Figure 11 and 12		-	-	1	µs
t_s	carrier storage time	I_{Con} = 5 A; I_{Bon} = I_{Boff} = 1 A; resistive load; Figure 11 and 12	[2]	-	-	4	µs
		I_{Con} = 5 A; I_{Bon} = 1 A; V_{CL} = 250 V; T_{mb} = 100 °C; inductive load; Figure 13 and 14		-	1.9	2.5	µs
t_f	fall time	I_{Con} = 5 A; I_{Bon} = I_{Boff} = 1 A; resistive load; Figure 11 and 12		-	-	0.8	µs
		I_{Con} = 5 A; I_{Bon} = 1 A; V_{CL} = 300 V; T_{mb} = 100 °C; inductive load; Figure 13 and 14		-	200	300	ns

[1] Measured with a half-sinewave voltage.

[2] turn-off storage time

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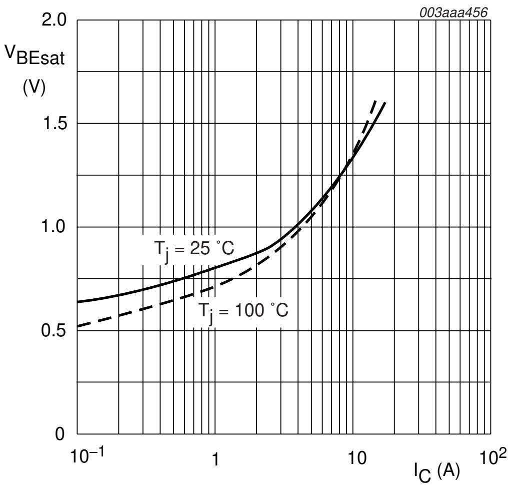
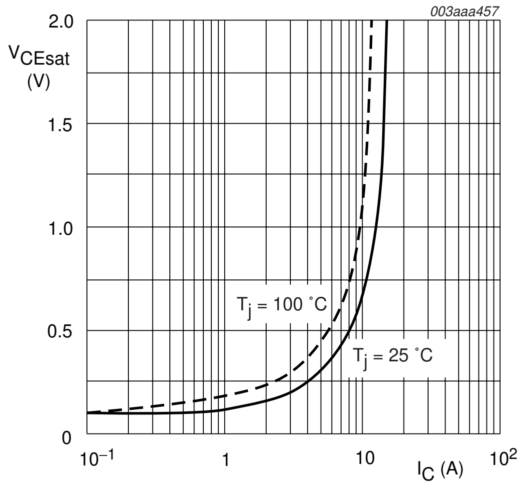


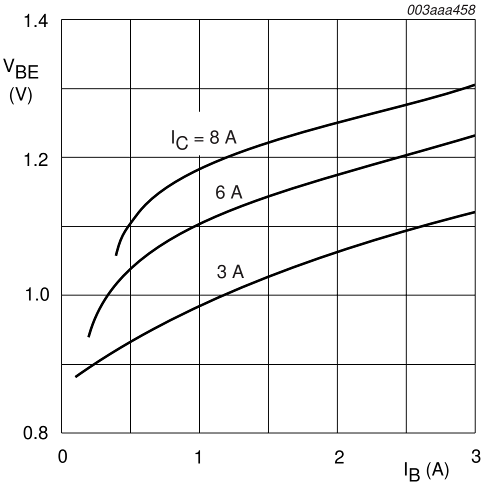
T_j = 25 °C and 100 °C

Fig 4. Base-emitter saturation voltage as a function of collector current; typical values.



T_j = 25 °C and 100 °C

Fig 5. Collector-emitter saturation voltage as a function of collector current; typical values.



T_j = 25 °C

Fig 6. Base-emitter voltage as a function of base current; typical values.

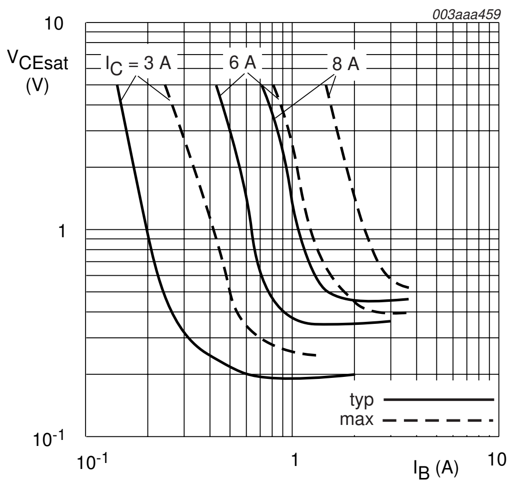


Fig 7. Collector-emitter saturation voltage as a function base current; typical and maximum values.

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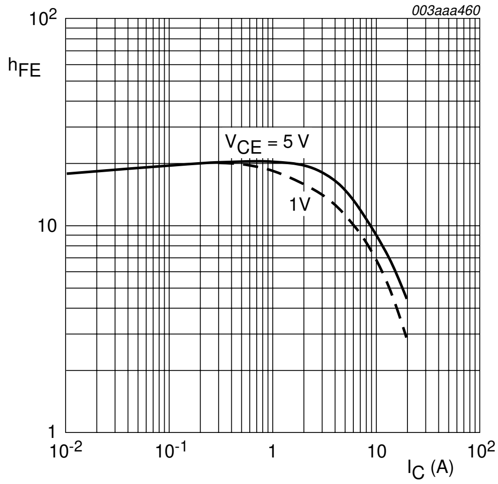

V_{CE} = 5 V and 1 V

Fig 8. DC current gain as a function of collector current; typical values.

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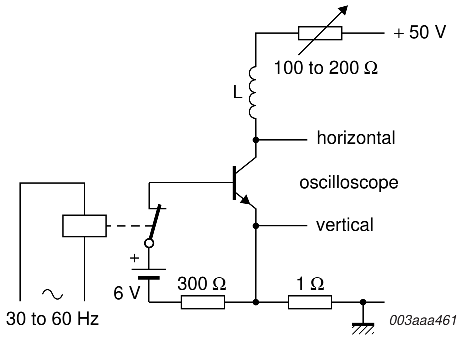


Fig 9. Test circuit for collector-emitter sustaining voltage.

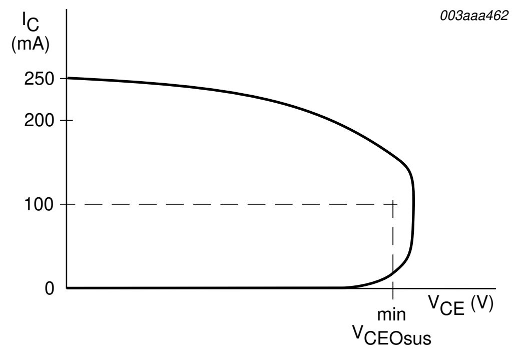
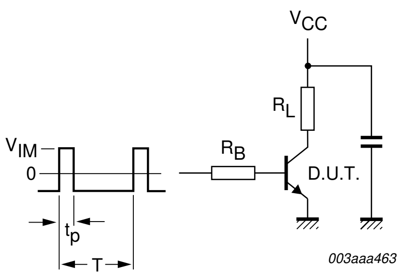


Fig 10. Oscilloscope display for collector-emitter sustaining voltage.



V_{CC} = 250 V; t_p = 20 µs; V_{IM} = –6 V to 8 V; t_p/T = 0.01.
The values of R_B and R_L are selected in accordance with I_{Con} and I_{Bon} requirements.

Fig 11. Test circuit for resistive load switching times

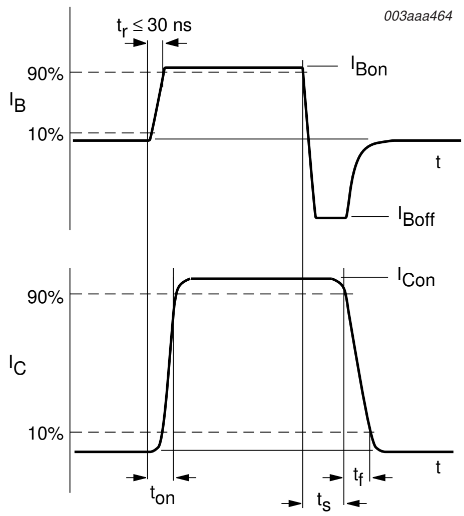


Fig 12. Switching time waveforms with resistive load.

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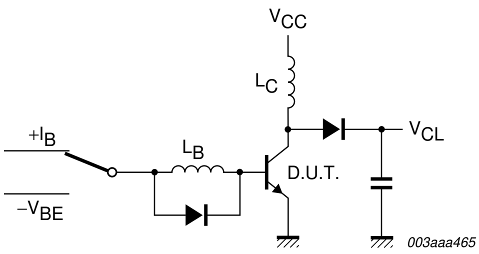

$V_{CL} \leq 1000$ V; $V_{CC} = 30$ V; $V_{BE} = -1$ V to -5 V;
$L_B = 1$ µH; $L_C = 200$ µH

Fig 13. Test circuit for inductive load switching and reverse bias safe operating area.

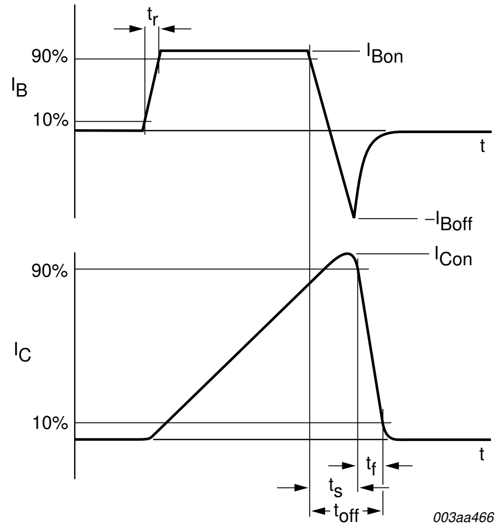

Fig 14. Switching time waveforms with inductive load.

7. Isolation characteristics

Table 6: Isolation characteristics

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$V_{isol(RMS)M}$	Peak RMS isolation voltage from all three terminals to external heatsink.	f = 50 to 60 Hz; sinusoidal waveform; RH ≤ 65%; clean and dust-free.	-	-	2500	V
$C_{c\text{-}h}$	Capacitance from collector to external heatsink.		-	12	-	pF

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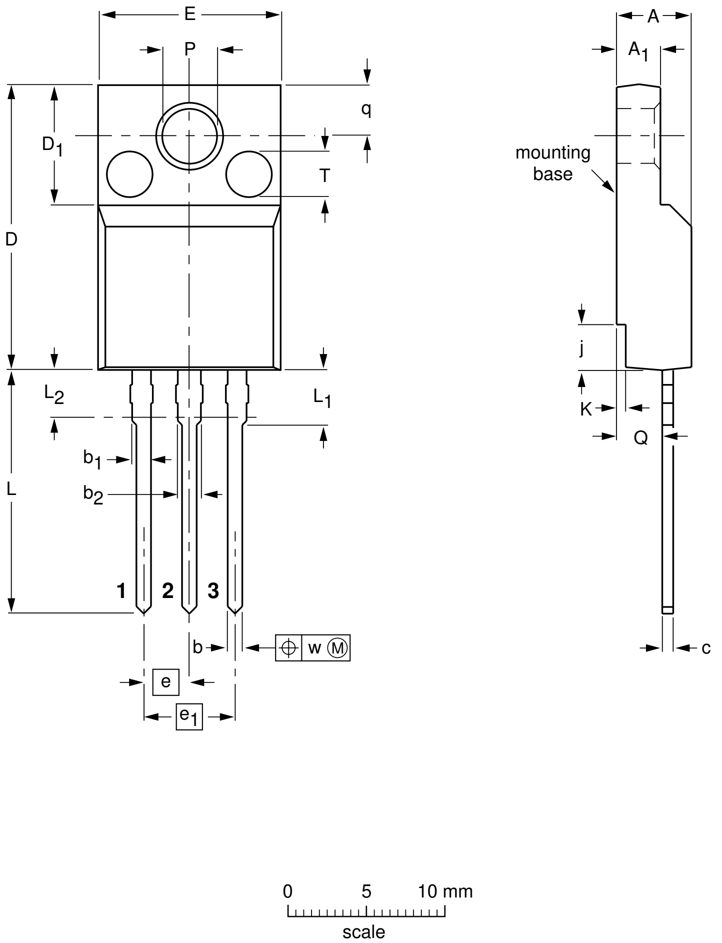
8. Package outline

Plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 3 lead TO-220 'full pack' **SOT186A**



DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1	b	b_1	b_2	c	D	D_1	E	e	e_1	j	K	L	L_1	L_2(1) max.	P	Q	q	T(2)	w
mm	4.6 4.0	2.9 2.5	0.9 0.7	1.1 0.9	1.4 1.0	0.7 0.4	15.8 15.2	6.5 6.3	10.3 9.7	2.54	5.08	2.7 1.7	0.6 0.4	14.4 13.5	3.30 2.79	3	3.2 3.0	2.6 2.3	3.0 2.6	2.5	0.4

Notes

1. Terminal dimensions within this zone are uncontrolled. Terminals in this zone are not tinned.
2. Both recesses are ∅ 2.5 × 0.8 max. depth

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT186A		3-lead TO-220F				~~02-03-12~~ 02-04-09

Fig 15. SOT186A (TO-220F).

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9. Revision history

Table 7: Revision history

Rev	Date	CPCN	Description
01	20040616	-	Product data (9397 750 13442)

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10. Data sheet status

Level	Data sheet status[1]	Product status[2][3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

11. Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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